



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



## 74VCX16835 Low Voltage 18-Bit Universal Bus Driver with 3.6V Tolerant Inputs and Outputs

### General Description

The VCX16835 low voltage 18-bit universal bus driver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched and clocked modes.

Data flow is controlled by output-enable ( $\overline{OE}$ ), latch-enable (LE), and clock (CLK) inputs. The device operates in Transparent Mode when LE is held HIGH. The device operates in clocked mode when LE is LOW and CLK is toggled. Data transfers from the Inputs ( $I_n$ ) to Outputs ( $O_n$ ) on a Positive Edge Transition of the Clock. When  $\overline{OE}$  is LOW, the output data is enabled. When  $\overline{OE}$  is HIGH the output port is in a high impedance state.

The 74VCX16835 is designed for low voltage (1.65V to 3.6V)  $V_{CC}$  applications with I/O capability up to 3.6V.

The 74VCX16835 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

### Features

- Compatible with PC100 DIMM module specifications
- 1.65V–3.6V  $V_{CC}$  supply operation
- 3.6V tolerant inputs and outputs
- $t_{PD}$  (CLK to  $O_n$ )
  - 4.2ns max for 3.0V to 3.6V  $V_{CC}$
  - 5.2ns max for 2.3V to 2.7V  $V_{CC}$
  - 9.2ns max for 1.65V to 1.95V  $V_{CC}$
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive ( $I_{OH}/I_{OL}$ )
  - $\pm 24mA$  @ 3.0V
  - $\pm 18mA$  @ 2.3V
  - $\pm 6mA$  @ 1.65V
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA) (Preliminary)

**Note 1:** To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  (OE to GND) through a pulldown resistor; the minimum value of the resistor is determined by the current sourcing capability of the driver.

### Ordering Code:

Order Number	Package Number	Package Description
74VCX16835GX (Note 2)	BGA54A (Preliminary)	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide [TAPE and REEL]
74VCX16835MTD (Note 3)	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

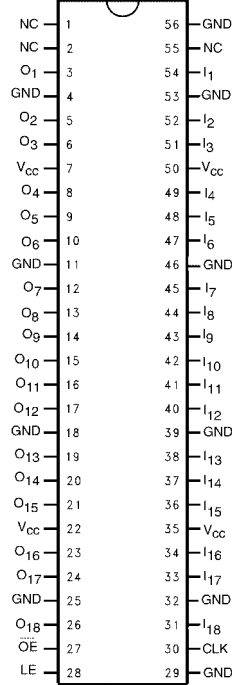
**Note 2:** BGA package available in Tape and Reel only.

**Note 3:** Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

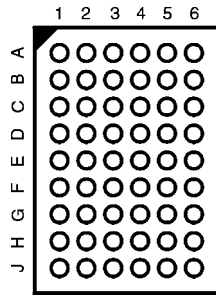
74VCX16835 Low Voltage 18-Bit Universal Bus Driver with 3.6V Tolerant Inputs and Outputs

### Connection Diagrams

Pin Assignment for TSSOP



Pin Assignment for FBGA



(Top Thru View)

### Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
LE	Latch Enable Input
CLK	Clock Input
I <sub>1</sub> - I <sub>18</sub>	Data Inputs
O <sub>1</sub> - O <sub>18</sub>	3-STATE Outputs
NC	No Connect

### FBGA Pin Assignments

	1	2	3	4	5	6
<b>A</b>	O <sub>2</sub>	O <sub>1</sub>	NC	GND	I <sub>1</sub>	I <sub>2</sub>
<b>B</b>	O <sub>4</sub>	O <sub>3</sub>	NC	NC	I <sub>3</sub>	I <sub>4</sub>
<b>C</b>	O <sub>6</sub>	O <sub>5</sub>	V <sub>CC</sub>	V <sub>CC</sub>	I <sub>5</sub>	I <sub>6</sub>
<b>D</b>	O <sub>8</sub>	O <sub>7</sub>	GND	GND	I <sub>7</sub>	I <sub>8</sub>
<b>E</b>	O <sub>10</sub>	O <sub>9</sub>	GND	GND	I <sub>9</sub>	I <sub>10</sub>
<b>F</b>	O <sub>12</sub>	O <sub>11</sub>	GND	GND	I <sub>11</sub>	I <sub>12</sub>
<b>G</b>	O <sub>14</sub>	O <sub>13</sub>	V <sub>CC</sub>	V <sub>CC</sub>	I <sub>13</sub>	I <sub>14</sub>
<b>H</b>	O <sub>16</sub>	O <sub>15</sub>	$\overline{OE}$	CLK	I <sub>15</sub>	I <sub>16</sub>
<b>J</b>	O <sub>17</sub>	O <sub>18</sub>	LE	GND	I <sub>18</sub>	I <sub>17</sub>

### Truth Table

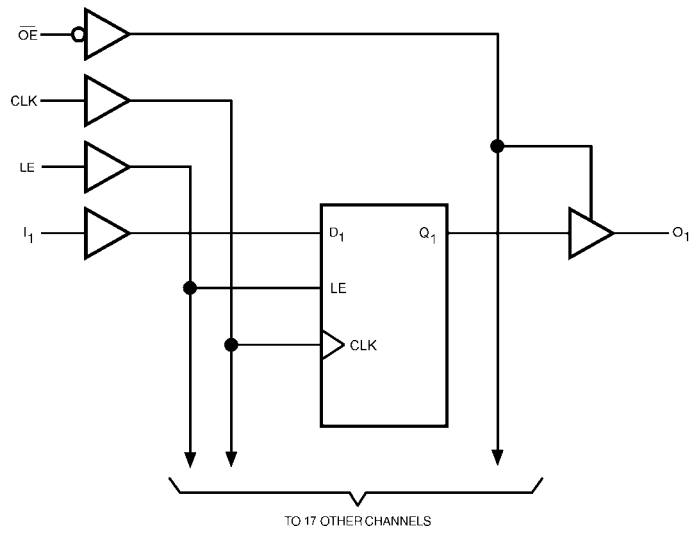
Inputs				Outputs
$\overline{OE}$	LE	CLK	I <sub>n</sub>	O <sub>n</sub>
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	↑	L	L
L	L	↑	H	H
L	L	H	X	O <sub>0</sub> (Note 4)
L	L	L	X	O <sub>0</sub> (Note 5)

H = Logic HIGH  
 L = Logic LOW  
 X = Don't Care, but not floating  
 Z = High Impedance  
 ↑ = LOW-to-HIGH Clock Transition

**Note 4:** Output level before the indicated steady-state input conditions were established provided that CLK was HIGH before LE went LOW.

**Note 5:** Output level before the indicated steady-state input conditions were established.

Logic Diagram



**Absolute Maximum Ratings** (Note 6)

Supply Voltage ( $V_{CC}$ )	-0.5V to +4.6V
DC Input Voltage ( $V_I$ )	-0.5V to +4.6V
Output Voltage ( $V_O$ )	
Outputs 3-STATE	-0.5V to +4.6V
Outputs Active (Note 7)	-0.5 to $V_{CC} + 0.5V$
DC Input Diode Current ( $I_{IK}$ ) $V_I < 0V$	-50 mA
DC Output Diode Current ( $I_{OK}$ )	
$V_O < 0V$	-50 mA
$V_O > V_{CC}$	+50 mA
DC Output Source/Sink Current	
( $I_{OH}/I_{OL}$ )	$\pm 50$ mA
DC $V_{CC}$ or Ground Current per	
Supply Pin ( $I_{CC}$ or Ground)	$\pm 100$ mA
Storage Temperature Range ( $T_{STG}$ )	-65°C to +150°C

**Recommended Operating Conditions** (Note 8)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	-0.3V to 3.6V
Output Voltage ( $V_O$ )	
Output in Active States	0V to $V_{CC}$
Output in 3-STATE	0V to 3.6V
Output Current in $I_{OH}/I_{OL}$	
$V_{CC} = 3.0V$ to 3.6V	$\pm 24$ mA
$V_{CC} = 2.3V$ to 2.7V	$\pm 18$ mA
$V_{CC} = 1.65V$ to 2.3V	$\pm 6$ mA
Free Air Operating Temperature ( $T_A$ )	-40°C to +85°C
Minimum Input Edge Rate ( $\Delta t/\Delta V$ )	
$V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$	10 ns/V

**Note 6:** The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

**Note 7:**  $I_O$  Absolute Maximum Rating must be observed.

**Note 8:** Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

**DC Electrical Characteristics (2.7V <  $V_{CC}$  ≤ 3.6V)**

Symbol	Parameter	Conditions	$V_{CC}$ (V)	Min	Max	Units
$V_{IH}$	HIGH Level Input Voltage		2.7-3.6	2.0		V
$V_{IL}$	LOW Level Input Voltage		2.7-3.6		0.8	V
$V_{OH}$	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.7-3.6	$V_{CC} - 0.2$		V
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
$V_{OL}$	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.7-3.6		0.2	V
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	
		$I_{OL} = 18 \text{ mA}$	3.0		0.4	
		$I_{OL} = 24 \text{ mA}$	3.0		0.55	
$I_I$	Input Leakage Current	$0V \leq V_I \leq 3.6V$	2.7-3.6		$\pm 5.0$	$\mu A$
$I_{OZ}$	3-STATE Output Leakage	$0V \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or $V_{IL}$	2.7-3.6		$\pm 10$	$\mu A$
$I_{OFF}$	Power Off Leakage Current	$0V \leq (V_I, V_O) \leq 3.6V$	0		10	$\mu A$
$I_{CC}$	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7-3.6		20	$\mu A$
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 9)		$\pm 20$		
$\Delta I_{CC}$	Increase in $I_{CC}$ per Input	$V_{IH} = V_{CC} - 0.6V$	2.7-3.6		750	$\mu A$

**Note 9:** Outputs disabled or 3-STATE only.

**DC Electrical Characteristics (2.3V ≤ V<sub>CC</sub> ≤ 2.7V)**

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Units
V <sub>IH</sub>	HIGH Level Input Voltage		2.3 - 2.7	1.6		V
V <sub>IL</sub>	LOW Level Input Voltage		2.3 - 2.7		0.7	V
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	2.3 - 2.7	V <sub>CC</sub> - 0.2		V
		I <sub>OH</sub> = -6 mA	2.3	2.0		
		I <sub>OH</sub> = -12 mA	2.3	1.8		
		I <sub>OH</sub> = -18 mA	2.3	1.7		
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.3 - 2.7		0.2	V
		I <sub>OL</sub> = 12mA	2.3		0.4	
		I <sub>OL</sub> = 18 mA	2.3		0.6	
I <sub>I</sub>	Input Leakage Current	0V ≤ V <sub>I</sub> ≤ 3.6V	2.3 - 2.7		±5.0	μA
I <sub>OZ</sub>	3-STATE Output Leakage	0V ≤ V <sub>O</sub> ≤ 3.6V	2.3 - 2.7		±10	μA
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
I <sub>OFF</sub>	Power Off Leakage Current	0V ≤ (V <sub>I</sub> , V <sub>O</sub> ) ≤ 3.6V	0		10	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>I</sub> = V <sub>CC</sub> or GND	2.3 - 2.7		20	μA
		V <sub>CC</sub> ≤ (V <sub>I</sub> , V <sub>O</sub> ) ≤ 3.6V (Note 10)	2.3 - 2.7		±20	

**Note 10:** Outputs disabled or 3-STATE only.

**DC Electrical Characteristics (1.65V ≤ V<sub>CC</sub> < 2.3V)**

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Units
V <sub>IH</sub>	HIGH Level Input Voltage		1.65 - 2.3	0.65 × V <sub>CC</sub>		V
V <sub>IL</sub>	LOW Level Input Voltage		1.65 - 2.3		0.35 × V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	1.65 - 2.3	V <sub>CC</sub> - 0.2		V
		I <sub>OH</sub> = -6 mA	1.65	1.25		
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	1.65 - 2.3		0.2	V
		I <sub>OL</sub> = 6mA	1.65		0.3	
I <sub>I</sub>	Input Leakage Current	0V ≤ V <sub>I</sub> ≤ 3.6V	1.65 - 2.3		±5.0	μA
I <sub>OZ</sub>	3-STATE Output Leakage	0V ≤ V <sub>O</sub> ≤ 3.6V	1.65 - 2.3		±10	μA
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
I <sub>OFF</sub>	Power Off Leakage Current	0V ≤ (V <sub>I</sub> , V <sub>O</sub> ) ≤ 3.6V	0		10	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>I</sub> = V <sub>CC</sub> or GND	1.65 - 2.3		20	μA
		V <sub>CC</sub> ≤ (V <sub>I</sub> , V <sub>O</sub> ) ≤ 3.6V (Note 11)			±20	

**Note 11:** Outputs disabled or 3-STATE only.

## AC Electrical Characteristics (Note 12)

Symbol	Parameter	$T_A = -40^\circ\text{C to } +85^\circ\text{C}, C_L = 30\text{ pF}, R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
$f_{MAX}$	Maximum Clock Frequency	250		200		100		MHz
$t_{PHL}, t_{PLH}$	Propagation Delay Bus to Bus	0.6	3.3	0.8	4.2	1.5	8.4	ns
$t_{PHL}, t_{PLH}$	Propagation Delay Clock to Bus	1.4	4.2	1.5	5.2	2.0	9.2	ns
$t_{PHL}, t_{PLH}$	Propagation Delay LE to Bus	0.6	3.8	0.8	4.9	1.5	9.8	ns
$t_{PZL}, t_{PZH}$	Output Enable Time	0.6	3.8	0.8	4.9	1.5	9.8	ns
$t_{PLZ}, t_{PHZ}$	Output Disable Time	0.6	3.9	0.8	4.5	1.5	7.6	ns
$t_S$	Setup Time	1.5		1.5		2.5		ns
$t_H$	Hold Time	0.7		0.7		1.0		ns
$t_W$	Pulse Width	1.5		1.5		4.0		ns
$t_{OSHL}, t_{OSLH}$	Output to Output Skew (Note 13)		0.5		0.5		0.75	ns

**Note 12:** For  $C_L=50\text{pF}$ , add approximately 300ps to the AC maximum specification.

**Note 13:** Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW ( $t_{OSHL}$ ) or LOW-to-HIGH ( $t_{OSLH}$ ).

## AC Electrical Characteristics Over Load (Note 14)

Symbol	Parameter	$T_A = -0^\circ\text{C to } +85^\circ\text{C}, R_L = 500\Omega, V_{CC} = 3.3V \pm 0.15V$				Units
		$C_L = 0\text{ pF}$		$C_L = 50\text{ pF}$		
		Min	Max	Min	Max	
$t_{PHL}, t_{PLH}$	Propagation Delay Bus to Bus	0.7	2.1	1.0	3.6	ns
$t_{PHL}, t_{PLH}$	Propagation Delay Clock to Bus	1.5	3.0	1.7	4.5	ns
$t_{PHL}, t_{PLH}$	Propagation Delay LE to Bus	0.7	2.6	1.0	4.1	ns
$t_{PZL}, t_{PZH}$	Output Enable Time	0.7	2.6	1.0	4.1	ns
$t_{PLZ}, t_{PHZ}$	Output Disable Time	0.7	2.7	1.0	4.2	ns
$t_{PHL}, t_{PLH}$	SSO Prop Delay Clock to Bus (Note 15)	1.5	3.3			ns
$t_S$	Setup Time	1.5		1.5		ns
$t_H$	Hold Time	0.7		0.7		ns

**Note 14:** This parameter is guaranteed by characterization but not tested.

**Note 15:** SSO = Simultaneous Switching Output. Any output combination of LOW-to-HIGH and/or HIGH-to-LOW transition.

## Dynamic Switching Characteristics

Symbol	Parameter	Conditions	$V_{CC}$ (V)	$T_A = +25^\circ\text{C}$	Units
				Typical	
$V_{OLP}$	Quiet Output Dynamic Peak $V_{OL}$	$C_L = 30\text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8 2.5 3.3	0.35 0.7 0.9	V
$V_{OLV}$	Quiet Output Dynamic Valley $V_{OL}$	$C_L = 30\text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8 2.5 3.3	-0.35 -0.7 -0.9	V
$V_{OHV}$	Quiet Output Dynamic Valley $V_{OH}$	$C_L = 30\text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8 2.5 3.3	1.3 1.7 2.0	V

## Capacitance

Symbol	Parameter	Conditions	T <sub>A</sub> = +25°C	
			Typical	Units
C <sub>IN</sub>	Input Capacitance	V <sub>I</sub> = 0V or V <sub>CC</sub> ; V <sub>CC</sub> = 1.8V, 2.5V, or 3.3V,	3.5	pF
C <sub>I/O</sub>	Input/Output Capacitance	V <sub>I</sub> = 0V, or V <sub>CC</sub> ; V <sub>CC</sub> = 1.8V, 2.5V or 3.3V	5.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	V <sub>I</sub> = 0V or V <sub>CC</sub> ; f = 10 MHz; V <sub>CC</sub> = 1.8V, 2.5V or 3.3V	13	pF

## I<sub>OUT</sub> - V<sub>OUT</sub> Characteristics

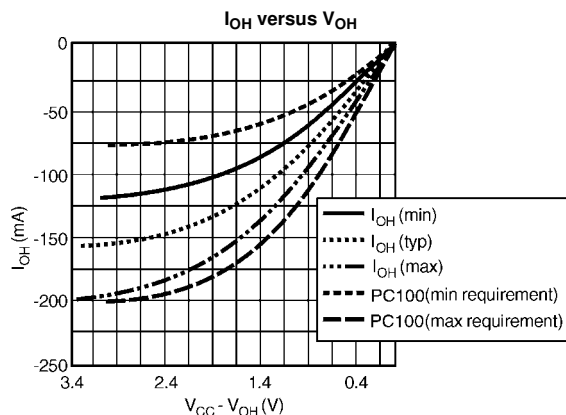


FIGURE 1. Characteristics for Output - Pull Up Driver

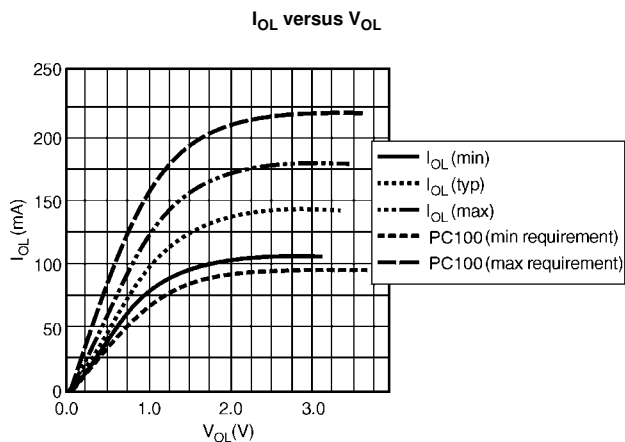


FIGURE 2. Characteristics for Output - Pull Down Driver



## AC Loading and Waveforms

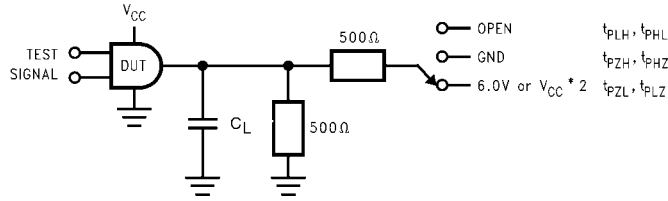


FIGURE 3. AC Test Circuit

TEST	SWITCH
$t_{PLH}, t_{PHL}$	Open
$t_{PZL}, t_{PLZ}$	6V at $V_{CC} = 3.3 \pm 0.3V$ ; $V_{CC} \times 2$ at $V_{CC} = 2.5 \pm 0.2V; 1.8V$ to $\pm 0.15V$
$t_{PZH}, t_{PHZ}$	GND

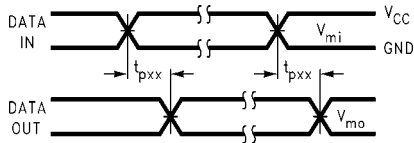


FIGURE 4. Waveform for Inverting and Non-inverting Functions  
 $t_r = t_f \leq 2.0ns, 10\%$  to  $90\%$

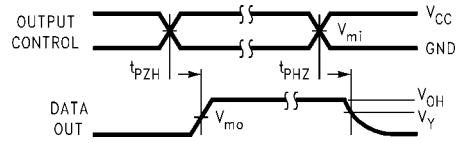


FIGURE 5. 3-STATE Output High Enable and Disable Times for Low Voltage Logic  
 $t_r = t_f \leq 2.0ns, 10\%$  to  $90\%$

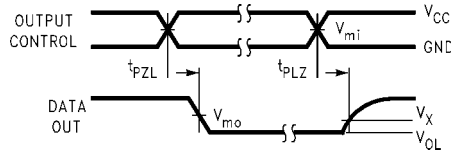
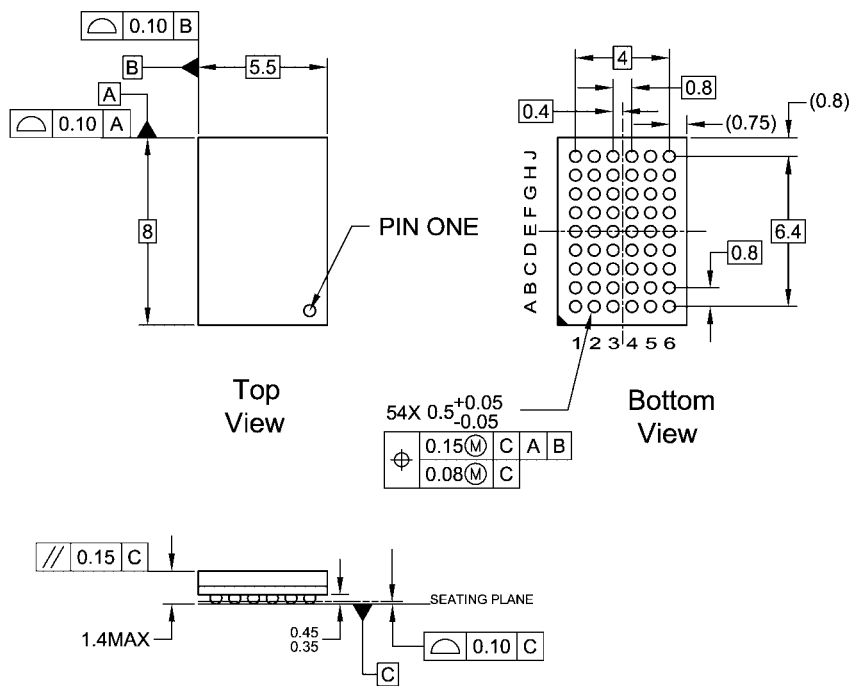


FIGURE 6. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic  
 $t_r = t_f \leq 2.0ns, 10\%$  to  $90\%$

Symbol	$V_{CC}$		
	$3.3V \pm 0.3V$	$2.5V \pm 0.2V$	$1.8 \pm 0.15V$
$V_{mi}$	1.5V	$V_{CC}/2$	$V_{CC}/2$
$V_{mo}$	1.5V	$V_{CC}/2$	$V_{CC}/2$
$V_x$	$V_{OL} + 0.3V$	$V_{OL} + 0.15V$	$V_{OL} + 0.15V$
$V_y$	$V_{OH} - 0.3V$	$V_{OH} - 0.15V$	$V_{OH} - 0.15V$

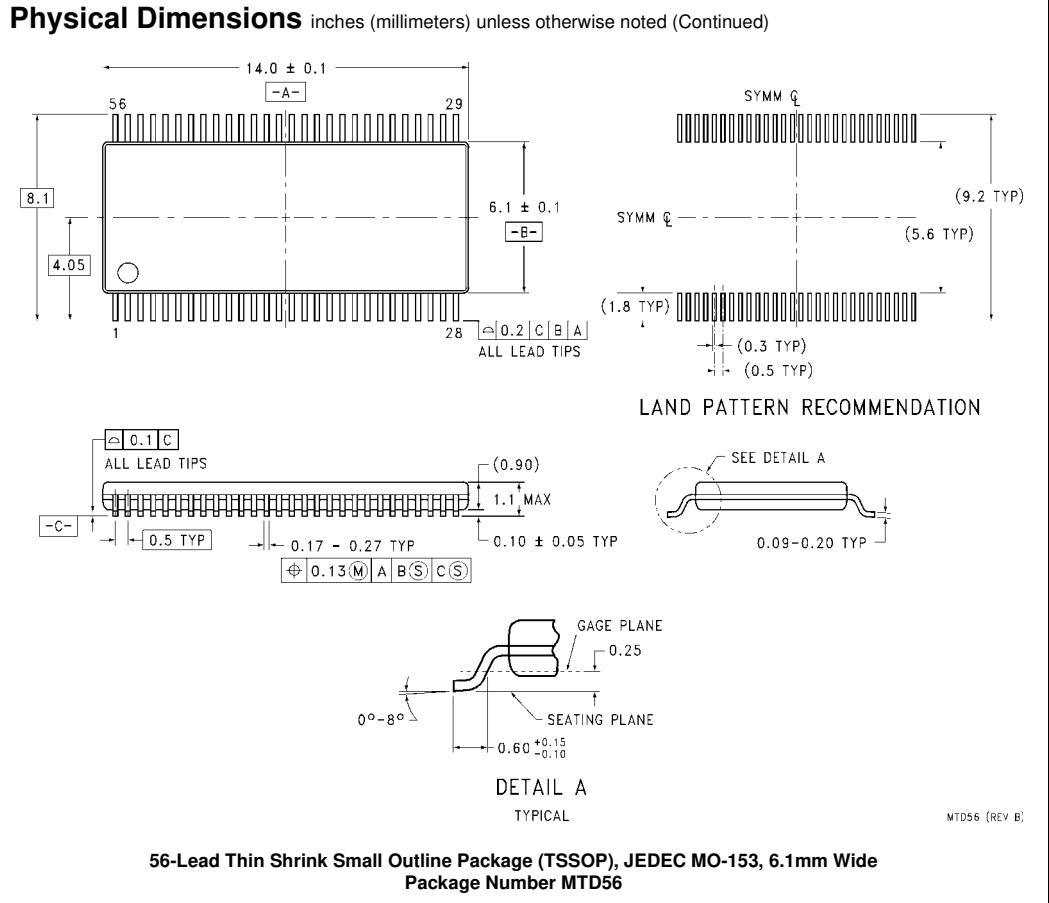
**Physical Dimensions** inches (millimeters) unless otherwise noted



- NOTES:
- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
  - B. ALL DIMENSIONS IN MILLIMETERS
  - C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)  
.35MM DIA PADS WITH A SOLDERMASK OPENING OF .45MM CONCENTRIC TO PADS
  - D. DRAWING CONFORMS TO ASME Y14.5M-1994

BGA54ArevD

**54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC M0-205, 5.5mm Wide  
Package Number BGA54A  
Preliminary**



Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.

**LIFE SUPPORT POLICY**

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

[www.fairchildsemi.com](http://www.fairchildsemi.com)